

# SWITCHMODE

## Schottky Power Rectifier

### MBRB8H100T4G, NBRB8H100T4G

#### Surface Mount Power Package

This series of Power Rectifiers employs the Schottky Barrier principle in a large metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for use in low voltage, high frequency switching power supplies, free wheeling diodes, and polarity protection diodes.

#### Features

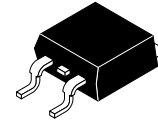
- Guardring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Short Heat Sink Tab Manufactured – Not Sheared!
- AEC-Q101 Qualified and PPAP Capable
- NBRB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free\*

#### Mechanical Characteristics:

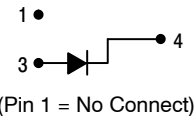
- Case: Epoxy, Molded, Epoxy Meets UL 94 V-0
- Weight: 1.7 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL1 Requirements
- ESD Ratings:
  - ◆ Machine Model = C (> 400 V)
  - ◆ Human Body Model = 3B (> 8000 V)

## SCHOTTKY BARRIER RECTIFIER

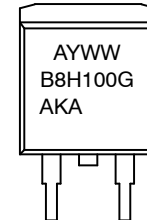
### 8 AMPERES, 100 VOLTS



D<sup>2</sup>PAK  
CASE 418B



#### MARKING DIAGRAM



B8H100 = Specific Device Code  
 A = Assembly Location  
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package  
 AKA = Polarity Indicator

#### ORDERING INFORMATION

| Device       | Package                         | Shipping†            |
|--------------|---------------------------------|----------------------|
| MBRB8H100T4G | D <sup>2</sup> PAK<br>(Pb-Free) | 800 /<br>Tape & Reel |

#### DISCONTINUED (Note 1)

|              |                                 |                      |
|--------------|---------------------------------|----------------------|
| NBRB8H100T4G | D <sup>2</sup> PAK<br>(Pb-Free) | 800 /<br>Tape & Reel |
|--------------|---------------------------------|----------------------|

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](http://BRD8011/D).

1. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on [www.onsemi.com](http://www.onsemi.com).

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MBRB8H100T4G, NBRB8H100T4G

## MAXIMUM RATINGS

| Rating                                                                                                                              | Symbol                          | Value       | Unit             |
|-------------------------------------------------------------------------------------------------------------------------------------|---------------------------------|-------------|------------------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                              | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | 100         | V                |
| Average Rectified Forward Current<br>(Rated $V_R$ , $T_C = 171^\circ\text{C}$ )                                                     | $I_{F(AV)}$                     | 8           | A                |
| Peak Repetitive Forward Current<br>(Rated $V_R$ , Square Wave, 20 kHz) $T_C = 171^\circ\text{C}$                                    | $I_{FRM}$                       | 16          | A                |
| Max Nonrepetitive Peak Surge Current<br>(Surge applied at rated load conditions halfwave, single phase, 60 Hz, $25^\circ\text{C}$ ) | $I_{FSM}$                       | 250         | A                |
| Operating Junction and Storage Temperature Range (Note 1)                                                                           | $T_J, T_{stg}$                  | -65 to +175 | $^\circ\text{C}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

## THERMAL CHARACTERISTICS

| Characteristic                                                         | Symbol                             | Value     | Unit               |
|------------------------------------------------------------------------|------------------------------------|-----------|--------------------|
| Thermal Resistance<br>Junction-to-Case (Note 2)<br>Junction-to-Ambient | $R_{\theta JC}$<br>$R_{\theta JA}$ | 1.1<br>44 | $^\circ\text{C/W}$ |

2. When mounted using minimum recommended pad size on FR-4 board.

## ELECTRICAL CHARACTERISTICS

| Characteristic                                                                                                                                            | Symbol | Value        | Unit                |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------|--------|--------------|---------------------|
| Maximum Instantaneous Forward Voltage (Note 3)<br>( $I_F = 8\text{ A}$ , $T_J = 25^\circ\text{C}$ )<br>( $I_F = 8\text{ A}$ , $T_J = 125^\circ\text{C}$ ) | $V_F$  | 0.71<br>0.55 | V                   |
| Maximum Instantaneous Reverse Current (Note 3)<br>(Rated dc Voltage, $T_J = 25^\circ\text{C}$ )<br>(Rated dc Voltage, $T_J = 125^\circ\text{C}$ )         | $I_R$  | 4.5<br>5.3   | $\mu\text{A}$<br>mA |

## DYNAMIC CHARACTERISTICS (Per Leg)

|                                                                                         |       |     |    |
|-----------------------------------------------------------------------------------------|-------|-----|----|
| Capacitance<br>( $V_R = 4.0\text{ V}$ , $T_C = 25^\circ\text{C}$ , Frequency = 1.0 MHz) | $C_T$ | 600 | pF |
|-----------------------------------------------------------------------------------------|-------|-----|----|

3. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

# MBRB8H100T4G, NBRB8H100T4G

## TYPICAL CHARACTERISTICS

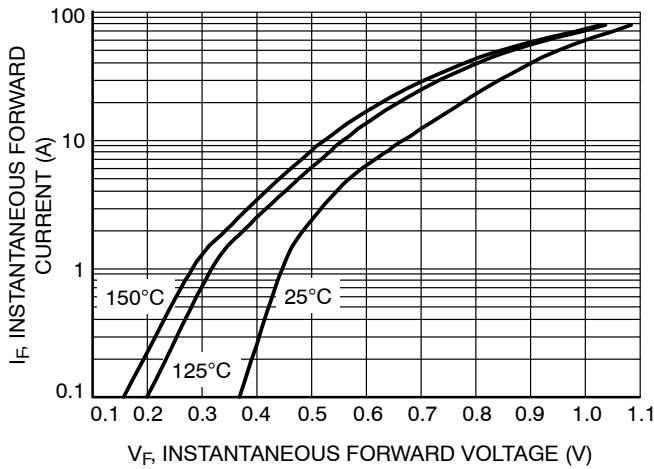


Figure 1. Typical Forward Voltage

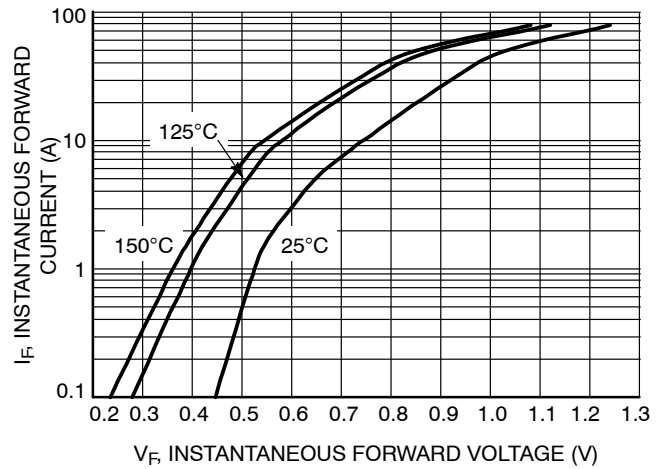


Figure 2. Maximum Forward Voltage

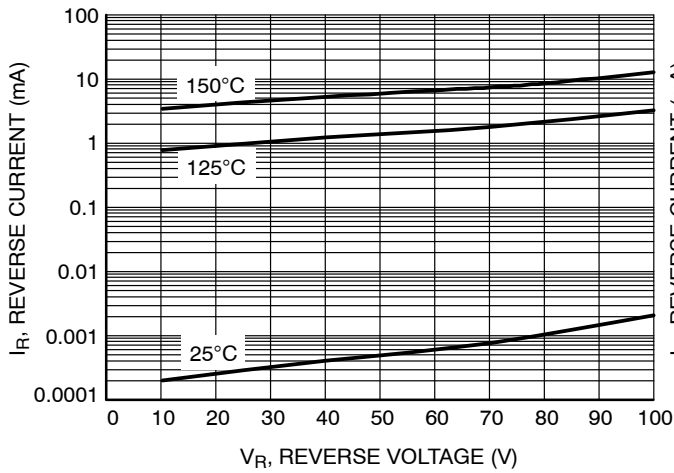


Figure 3. Typical Reverse Current

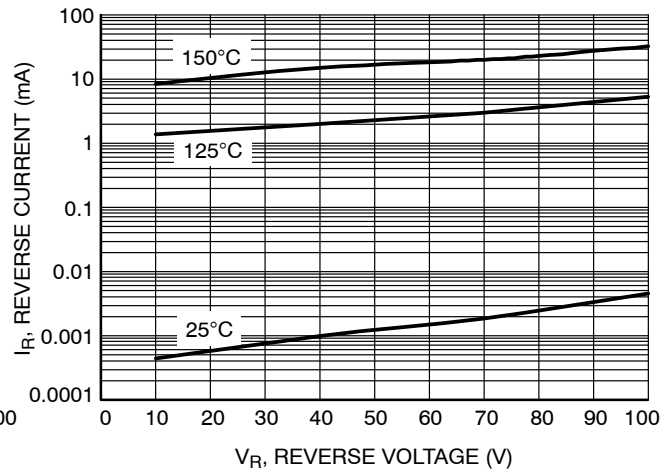


Figure 4. Maximum Reverse Current

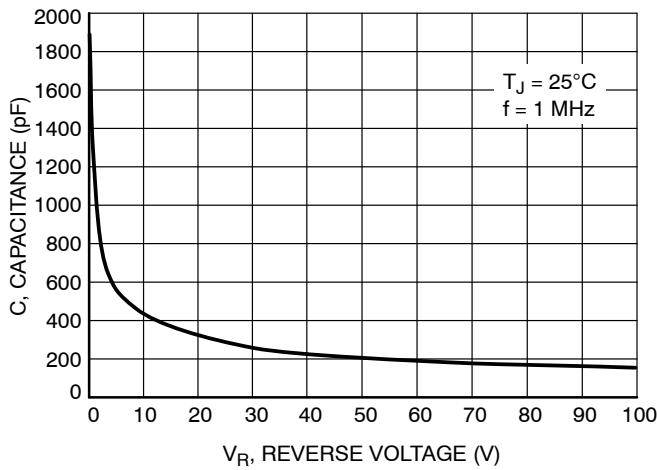


Figure 5. Typical Capacitance

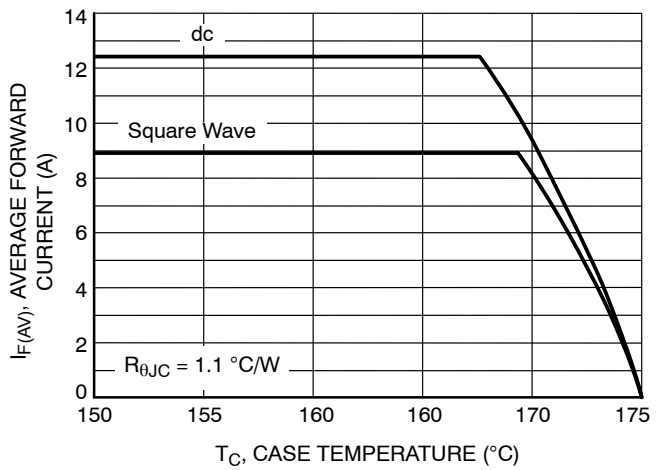


Figure 6. Current Derating, Case

# MBRB8H100T4G, NBRB8H100T4G

## TYPICAL CHARACTERISTICS

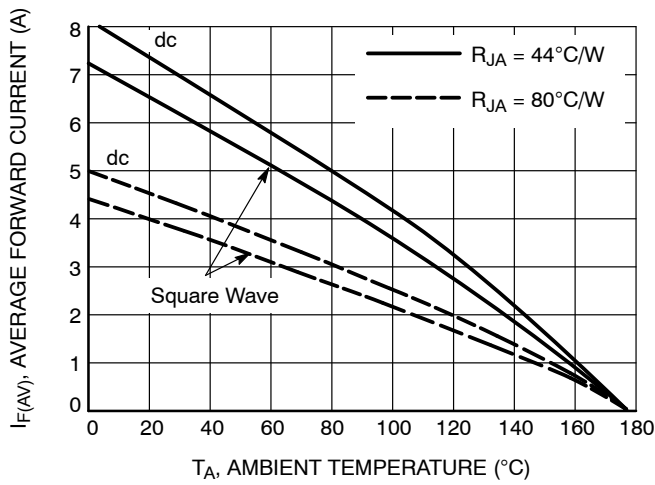


Figure 7. Current Derating, Ambient

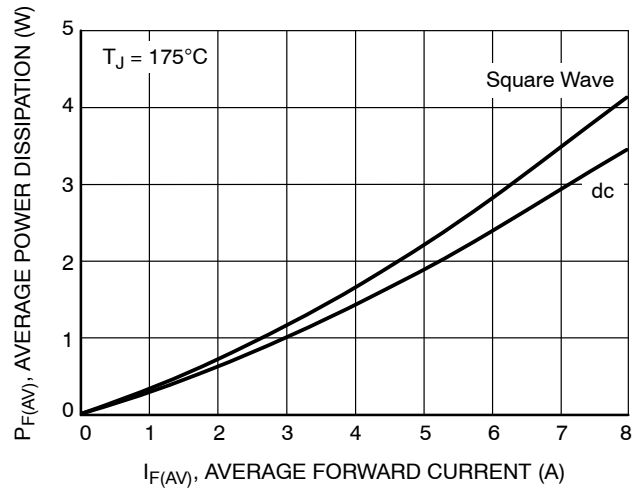


Figure 8. Typical Forward Power Dissipation

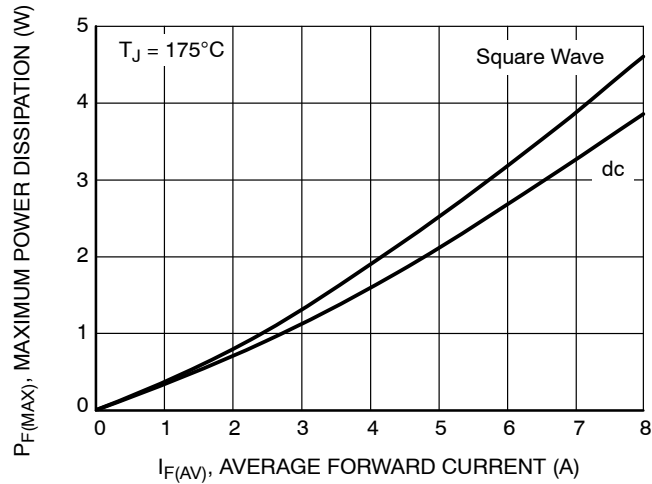


Figure 9. Maximum Forward Power Dissipation

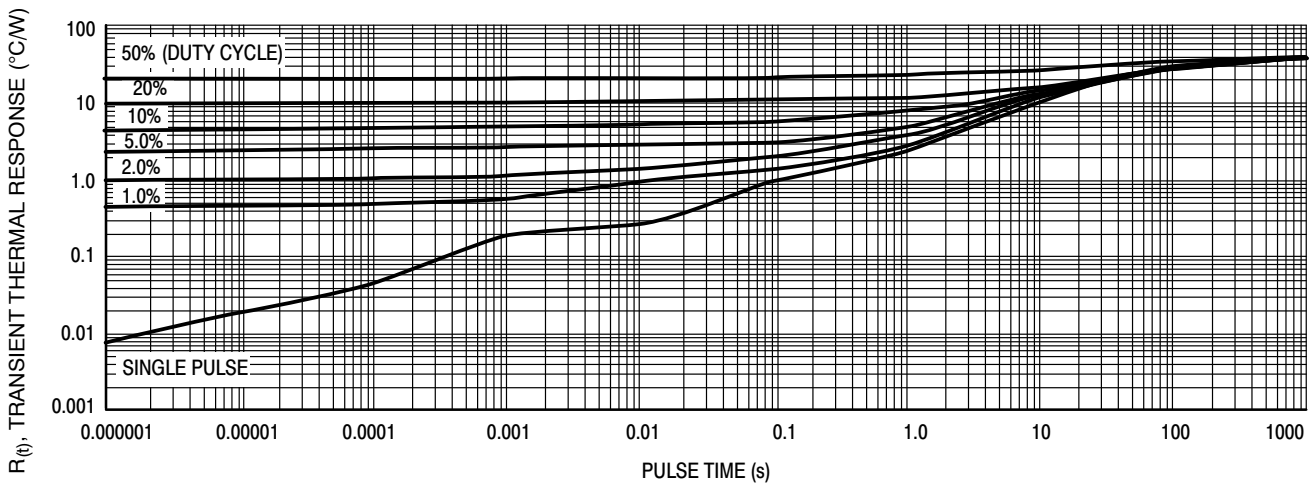
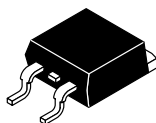


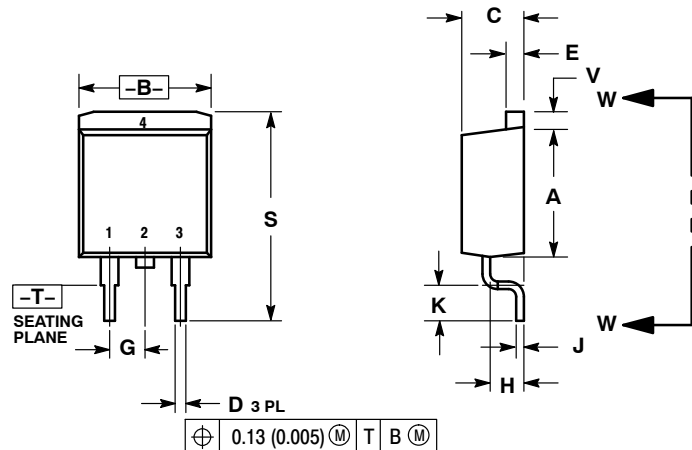
Figure 10. Thermal Response, Junction-to-Ambient



D<sup>2</sup>PAK 3  
CASE 418B-04  
ISSUE L

DATE 17 FEB 2015

SCALE 1:1

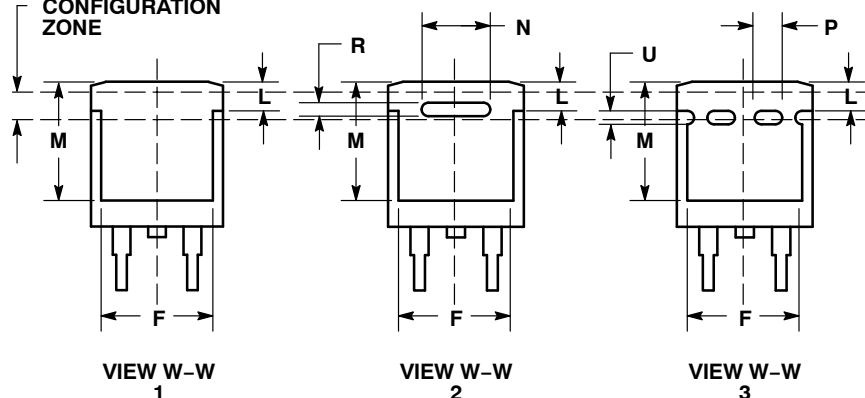


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

| DIM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN    | MAX   | MIN         | MAX   |
| A   | 0.340  | 0.380 | 8.64        | 9.65  |
| B   | 0.380  | 0.405 | 9.65        | 10.29 |
| C   | 0.160  | 0.190 | 4.06        | 4.83  |
| D   | 0.020  | 0.035 | 0.51        | 0.89  |
| E   | 0.045  | 0.055 | 1.14        | 1.40  |
| F   | 0.310  | 0.350 | 7.87        | 8.89  |
| G   | 0.100  | BSC   | 2.54        | BSC   |
| H   | 0.080  | 0.110 | 2.03        | 2.79  |
| J   | 0.018  | 0.025 | 0.46        | 0.64  |
| K   | 0.090  | 0.110 | 2.29        | 2.79  |
| L   | 0.052  | 0.072 | 1.32        | 1.83  |
| M   | 0.280  | 0.320 | 7.11        | 8.13  |
| N   | 0.197  | REF   | 5.00        | REF   |
| P   | 0.079  | REF   | 2.00        | REF   |
| R   | 0.039  | REF   | 0.99        | REF   |
| S   | 0.575  | 0.625 | 14.60       | 15.88 |
| V   | 0.045  | 0.055 | 1.14        | 1.40  |

VARIABLE  
CONFIGURATION  
ZONE



STYLE 1:

- PIN 1. BASE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR

STYLE 2:

- PIN 1. GATE  
2. DRAIN  
3. SOURCE  
4. DRAIN

STYLE 3:

- PIN 1. ANODE  
2. CATHODE  
3. ANODE  
4. CATHODE

STYLE 4:

- PIN 1. GATE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR

STYLE 5:

- PIN 1. CATHODE  
2. ANODE  
3. CATHODE  
4. ANODE

STYLE 6:

- PIN 1. NO CONNECT  
2. CATHODE  
3. ANODE  
4. CATHODE

MARKING INFORMATION AND FOOTPRINT ON PAGE 2

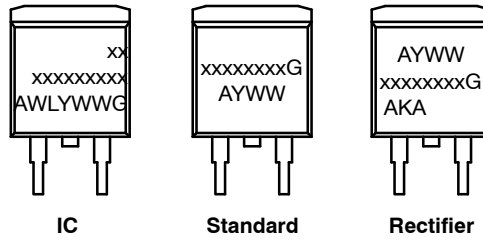
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**D<sup>2</sup>PAK 3**  
CASE 418B-04  
ISSUE L

DATE 17 FEB 2015

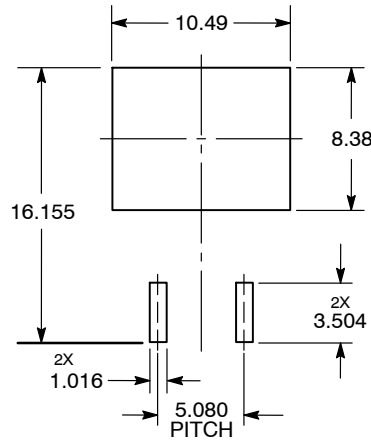
**GENERIC  
MARKING DIAGRAM\***



xx = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package  
AKA = Polarity Indicator

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

**SOLDERING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

|                         |                           |                                                                                                                                                                                     |
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